

# HIGH Voltage IGBT with Diode

**IXSH 15N120BD1**  
**IXST 15N120BD1**

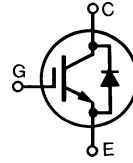
"S" Series - Improved SCSOA Capability

$$I_{C25} = 30 \text{ A}$$

$$V_{CES} = 1200 \text{ V}$$

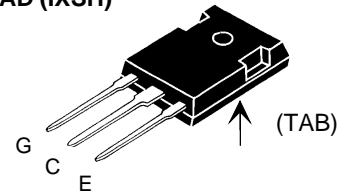
$$V_{CE(sat)} = 3.4 \text{ V}$$

Preliminary data

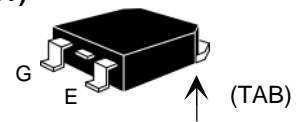


Symbol	Test Conditions	Maximum Ratings	
$V_{CES}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	1200	V
$V_{CGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GE} = 1 \text{ M}\Omega$	1200	V
$V_{GES}$	Continuous	$\pm 20$	V
$V_{GEM}$	Transient	$\pm 30$	V
$I_{C25}$	$T_C = 25^\circ\text{C}$	30	A
$I_{C90}$	$T_C = 90^\circ\text{C}$	15	A
$I_{CM}$	$T_C = 25^\circ\text{C}$ , 1 ms	60	A
<b>SSOA (RBSOA)</b>	$V_{GE} = 15 \text{ V}$ , $T_J = 125^\circ\text{C}$ , $R_G = 10 \Omega$ Clamped inductive load	$I_{CM} = 40$ @ $0.8 V_{CES}$	A
$t_{sc}$	$T_J = 125^\circ\text{C}$ , $V_{GE} = 720 \text{ V}$ ; $V_{GE} = 15 \text{ V}$ , $R_G = 10 \Omega$ Non repetitive	10	$\mu\text{s}$
$P_C$	$T_C = 25^\circ\text{C}$	150	W
$T_J$		-55 ... +150	$^\circ\text{C}$
$T_{JM}$		150	$^\circ\text{C}$
$T_{stg}$		-55 ... +150	$^\circ\text{C}$
$M_d$	Mounting torque (TO-247)	1.13/10	Nm/lb.in.
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	$^\circ\text{C}$
Maximum tab temperature for soldering (TO-268)		260	$^\circ\text{C}$
<b>Weight</b>	TO-247	6	g
	TO-268	4	g

TO-247 AD (IXSH)



TO-268 (IXST)



## Features

- High Blocking Voltage
- Epitaxial Silicon drift region
  - fast switching
  - small tail current
  - low switching losses
- MOS gate turn-on for drive simplicity
- Molding epoxies meet UL 94 V-0 flammability classification

## Applications

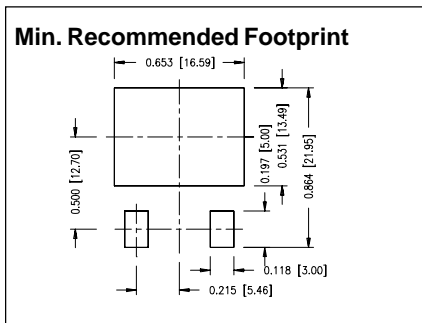
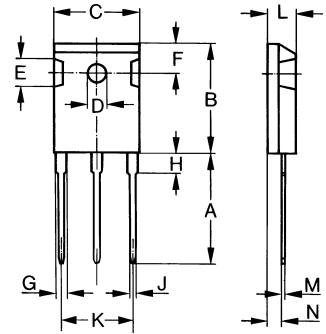
- AC motor speed control
- DC servo and robot drives
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- DC choppers

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$BV_{CES}$	$I_C = 1.0 \text{ mA}$ , $V_{GE} = 0 \text{ V}$	1200		V
$V_{GE(th)}$	$I_C = 250 \mu\text{A}$ , $V_{CE} = V_{GE}$	3		6 V
$I_{CES}$	$V_{CE} = 0.8 \cdot V_{CES}$ Note 1 $T_J = 125^\circ\text{C}$			50 $\mu\text{A}$ 2.5 mA
$I_{GES}$	$V_{CE} = 0 \text{ V}$ , $V_{GE} = \pm 20 \text{ V}$			$\pm 100 \text{ nA}$
$V_{CE(sat)}$	$I_C = I_{C90}$ , $V_{GE} = 15 \text{ V}$ Note 2 $T_J = 125^\circ\text{C}$	3.0	3.4	V
		2.8		V

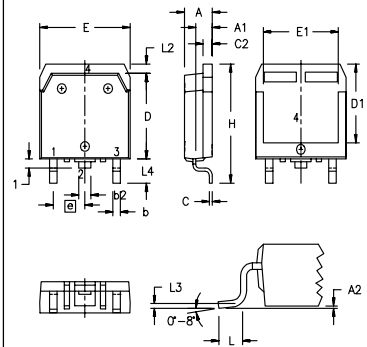
Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$g_{fs}$	$I_C = I_{C90}$ ; $V_{CE} = 10\text{ V}$ , Note 2	7	9.5	S
$C_{ies}$			1400	pF
$C_{oes}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		120	pF
$C_{res}$			37	pF
$Q_g$			57	nC
$Q_{ge}$	$I_C = I_{C90}$ , $V_{GE} = 15\text{ V}$ , $V_{CE} = 0.5 V_{CES}$		14	nC
$Q_{gc}$			25	nC
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b>		30	ns
$t_{ri}$	$I_C = I_{C90}$ , $V_{GE} = 15\text{ V}$		25	ns
$t_{d(off)}$	$R_G = 10\ \Omega$	148	300	ns
$t_{fi}$	$V_{CE} = 0.8 V_{CES}$ Note 3	126	250	ns
$E_{off}$		1.5	2.9	mJ
$t_{d(on)}$	<b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b>		30	ns
$t_{ri}$	$I_C = I_{C90}$ , $V_{GE} = 15\text{ V}$		25	ns
$E_{on}$	$R_G = 10\ \Omega$ , $V_{CE} = 0.8 V_{CES}$ Note 3		2.6	mJ
$t_{d(off)}$		265		ns
$t_{fi}$		298		ns
$E_{off}$		3.1		mJ
$R_{thJC}$			0.83	K/W
$R_{thCK}$	(TO-247)	0.25		K/W

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$V_F$	$I_F = I_{C90}$ ; $V_{GE} = 0\text{ V}$ Note 2	$T_J = 150^\circ\text{C}$	1.7	V
		$T_J = 25^\circ\text{C}$	2.5	V
$I_{RM}$	$I_F = 30\text{ A}$ ; $V_{GE} = 0\text{ V}$ ; $T_J = 100^\circ\text{C}$ $V_R = 100\text{ V}$ ; $-di_F/dt = 100\text{ A}/\mu\text{s}$		5.5	A
$t_{rr}$	$I_F = 1\text{ A}$ ; $-di/dt = 200\text{ A}/\mu\text{s}$ ; $V_R = 30\text{ V}$ $T_J = 25^\circ\text{C}$		30	ns
$R_{thJC}$			0.9	K/W

- Notes: 1. Device must be heatsunk for high temperature leakage current measurements to avoid thermal runaway.  
 2. Pulse test,  $t \leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$   
 3. Switching times may increase for  $V_{CE}(\text{Clamp}) > 0.8 \cdot V_{CES}$ , higher  $T_J$  or increased  $R_G$ .


**TO-247 AD (IXSH) Outline**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

**TO-268AA (D<sup>3</sup> PAK)**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.9	5.1	.193	.201
A <sub>1</sub>	2.7	2.9	.106	.114
A <sub>2</sub>	.02	.25	.001	.010
b	1.15	1.45	.045	.057
b <sub>2</sub>	1.9	2.1	.75	.83
C	.4	.65	.016	.026
D	13.80	14.00	.543	.551
E	15.85	16.05	.624	.632
E <sub>1</sub>	13.3	13.6	.524	.535
e	5.45 BSC		.215 BSC	
H	18.70	19.10	.736	.752
L	2.40	2.70	.094	.106
L <sub>1</sub>	1.20	1.40	.047	.055
L <sub>2</sub>	1.00	1.15	.039	.045
L <sub>3</sub>	0.25 BSC		.010 BSC	
L <sub>4</sub>	3.80	4.10	.150	.161